MJE5742 is a Preferred Device

NPN Silicon Power Darlington Transistors

The MJE5740 and MJE5742 Darlington transistors are designed for high-voltage power switching in inductive circuits.

Features

• Pb-Free Packages are Available*

Applications

- Small Engine Ignition
- Switching Regulators
- Inverters
- Solenoid and Relay Drivers
- Motor Controls

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage MJE5740 MJE5742	V _{CEO(sus)}	300 400	Vdc
Collector–Emitter Voltage MJE5740 MJE5742	V _{CEV}	600 800	Vdc
Emitter-Base Voltage	V _{EB}	8	Vdc
Collector Current – Continuous – Peak (Note 1)	I _C I _{CM}	8 16	Adc
Base Current – Continuous – Peak (Note 1)	I _B I _{BM}	2.5 5	Adc
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2 16	W W/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	80 640	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.25	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	TL	275	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle ≤ 10%.

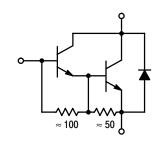
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



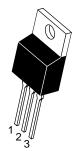
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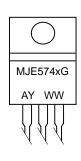
POWER DARLINGTON TRANSISTORS 8 AMPERES 300-400 VOLTS 80 WATTS



MARKING DIAGRAM



TO-220AB CASE 221A-09 STYLE 1



 $\begin{array}{ll} \text{MJE574x} &= \text{Device Code} \\ & x = 0 \text{ or } 2 \\ \text{G} &= \text{Pb-Free Package} \end{array}$

A = Assembly Location
Y = Year

Y = Year WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS (Note 2)			•		
	V _{CEO(sus)}	300 400	- -	- -	Vdc
Collector Cutoff Current (V _{CEV} = Rated Value, V _{BE(off)} = 1.5 Vdc) (V _{CEV} = Rated Value, V _{BE(off)} = 1.5 Vdc, T _C = 100°C)	I _{CEV}	- -	- -	1 5	mAdc
Emitter Cutoff Current (V _{EB} = 8 Vdc, I _C = 0)	I _{EBO}	-	_	75	mAdc
SECOND BREAKDOWN			•		
Second Breakdown Collector Current with Base Forward Biased		See Figure 6			
Clamped Inductive SOA with Base Reverse Biased		See Figure 7			
ON CHARACTERISTICS (Note 2)					
DC Current Gain ($I_C = 0.5$ Adc, $V_{CE} = 5$ Vdc) ($I_C = 4$ Adc, $V_{CE} = 5$ Vdc)	h _{FE}	50 200	100 400	_ _	_
Collector–Emitter Saturation Voltage (I_C = 4 Adc, I_B = 0.2 Adc) (I_C = 8 Adc, I_B = 0.4 Adc) (I_C = 4 Adc, I_B = 0.2 Adc, T_C = 100°C)	V _{CE(sat)}	- - -	- - -	2 3 2.2	Vdc
Base–Emitter Saturation Voltage (I_C = 4 Adc, I_B = 0.2 Adc) (I_C = 8 Adc, I_B = 0.4 Adc) (I_C = 4 Adc, I_B = 0.2 Adc, I_C = 100°C)	V _{BE(sat)}	- - -	- - -	2.5 3.5 2.4	Vdc
Diode Forward Voltage (Note 3) (I _F = 5 Adc)	V _f	-	_	2.5	Vdc
SWITCHING CHARACTERISTICS		1		1	•
Typical Resistive Load (Table 1)					
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Typical Resistive Load (Table 1)						
Delay Time		t _d	_	0.04	_	μs
Rise Time	$(V_{CC} = 250 \text{ Vdc}, I_{C(pk)} = 6 \text{ A} $ $I_{B1} = I_{B2} = 0.25 \text{ A}, t_p = 25 \mu s,$	t _r	-	0.5	-	μs
Storage Time	i _{B1} = i _{B2} = 0.25 A, t _p = 25 μs, Duty Cycle ≤ 1%)	t _s	-	8	-	μs
Fall Time		t _f	-	2	-	μs
Inductive Load, Clamped (Table 1)						
Voltage Storage Time	(I _{C(pk)} = 6 A, V _{CE(pk)} = 250 Vdc	t _{sv}	_	4	_	μS
Crossover Time	$(I_{C(pk)} = 6 \text{ A}, V_{CE(pk)} = 250 \text{ Vdc}$ $I_{B1} = 0.06 \text{ A}, V_{BE(off)} = 5 \text{ Vdc})$	t _c	-	2	-	μS

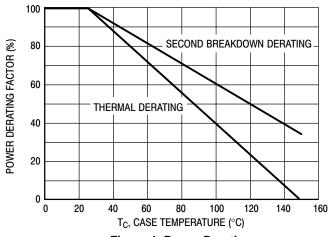
^{2.} Pulse Test: Pulse Width 300 μ s, Duty Cycle = 2%.

ORDERING INFORMATION

Device	Package	Shipping
MJE5740	TO-220	
MJE5740G	TO-220 (Pb-Free)	FOLIN'S / Dell
MJE5742	TO-220	50 Units / Rail
MJE5742G	TO-220 (Pb-Free)	

^{3.} The internal Collector–to–Emitter diode can eliminate the need for an external diode to clamp inductive loads. Tests have shown that the Forward Recovery Voltage (V_f) of this diode is comparable to that of typical fast recovery rectifiers.

TYPICAL CHARACTERISTICS



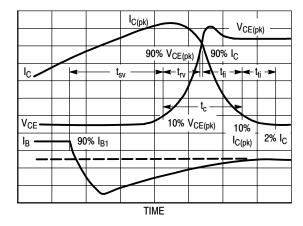
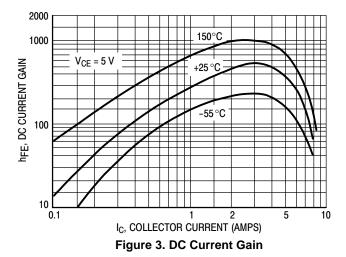


Figure 1. Power Derating Figure 2. Inductive Switching Measurements



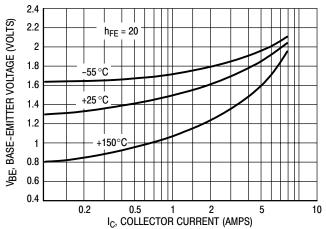
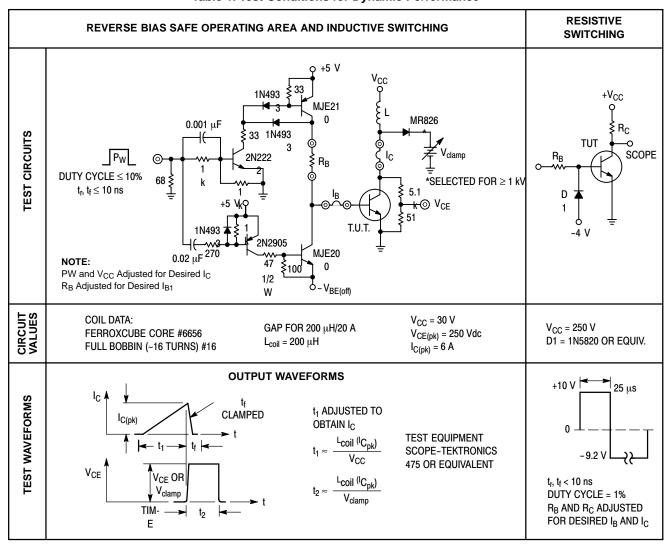


Figure 4. Base-Emitter Voltage

Table 1. Test Conditions for Dynamic Performance



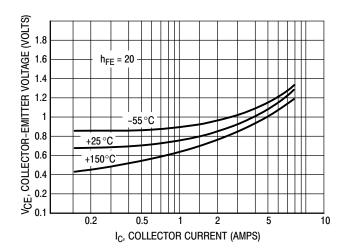


Figure 5. Inductive Switching Measurements

SAFE OPERATING AREA INFORMATION

FORWARD BIAS

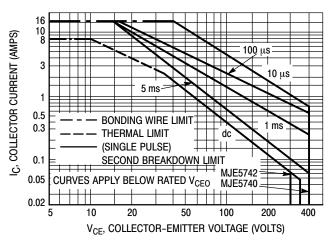
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_C = 25^{\circ}C$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C \ge 25^{\circ}C$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Figure 6 may be found at any case temperature by using the appropriate curve on Figure 1.

REVERSE BIAS

For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current condition allowable during reverse biased turnoff. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 7 gives the complete RBSOA characteristics.

The Safe Operating Area figures shown in Figures 6 and 7 are specified ratings for these devices under the test conditions shown.



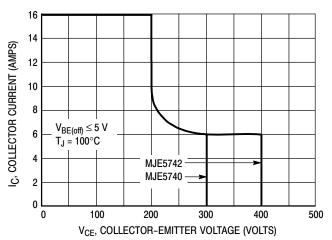


Figure 6. Forward Bias Safe Operating Area

Figure 7. Reverse Bias Safe Operating Area

RESISTIVE SWITCHING PERFORMANCE

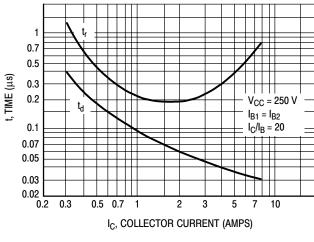


Figure 8. Turn-On Time

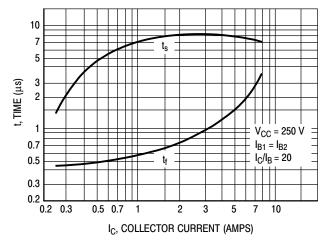
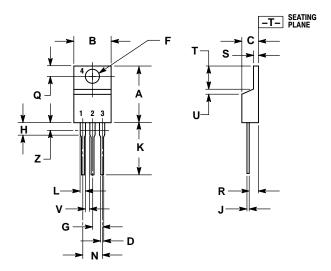


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE AA**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

STYLE 1:

PIN 1. BASE

- 2. COLLECTOR
- 3. EMITTER
- COLLECTOR

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